

ICS 31.200
CCS L 40



**NATIONAL STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

GB/T 42709.2-2026

**Semiconductor devices - Micro-electromechanical devices -
Part 2: Tensile testing method of thin film materials**

半导体器件 微电子机械器件 第2部分：薄膜材料拉伸试验方法

(English Translation)

Issued on: April 30, 2026

Implemented on: November 1, 2026

Issued by: State Administration for Market Regulation

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Foreword

This document complies with the provisions of GB/T 1.1-2020 "Standardization Work Guidelines Part 1: Structure and Drafting Rules of Standardization Documents".

Drafting.

This document is Part 2 of GB/T 42709 "Semiconductor Devices - Microelectromechanical Devices". GB/T 42709 has been published as follows.

Part 2.

---Part 2: Methods for tensile testing of thin film materials;

---Part 3: Standard test pieces for tensile testing of thin films;

---Part 5: Radio Frequency MEMS Switches;

---Part 7: MEMS Bulk Acoustic Filters and Duplexers for RF Control and Selection;

---Part 19: Electronic Compass.

This document is equivalent to IEC 62047-2:2006 "Semiconductor devices - Microelectromechanical devices - Part 2: Thin film materials - Tensile testing" method".

This document includes a new chapter on "Terms and Definitions".

Please note that some content in this document may involve patents. The issuing organization of this document assumes no responsibility for identifying patents.

This document was proposed by the Ministry of Industry and Information Technology of the People's Republic of China.

This document is under the jurisdiction of the National Integrated Circuit Standardization Technical Committee (SAC/TC599).

Introduction

This document specifies that for microelectromechanical systems (MEMS), micromechanical devices, and similar devices, the length and width must be less than 1 mm, and the thickness must be less than [missing information].

Tensile testing methods for 10 µm thin film structural materials.

This document adopts IEC 62047-2:2006, which will enable my country's testing methods in related fields to align with international standards and promote the development of my country's semiconductor industry.

The quality of the components has reached international standards.

GB/T 42709 "Semiconductor Devices and Microelectromechanical Devices" is proposed to consist of 22 parts.

---Part 2: Tensile Testing Methods for Thin Film Materials. The purpose is to specify tensile testing methods for MEMS thin film materials.

---Part 3: Standard Test Pieces for Tensile Testing of Thin Films. The purpose is to specify the test pieces for tensile testing of MEMS thin film materials.

Relevant requirements.

---Part 5: Radio Frequency MEMS Switches. The purpose is to define the terminology, characteristic requirements, and test methods for radio frequency MEMS switches.

Laws, etc.

---Part 6: Axial Fatigue Testing Methods for Thin Film Materials. The purpose is to specify axial fatigue testing methods for MEMS thin film materials.

method.

---Part 7: MEMS Bulk Acoustic Filters and Duplexers for RF Control and Selection. The purpose is to specify MEMS bulk acoustic filters and duplexers.

Terminology, characteristics, and testing methods for acoustic resonators, filters, and duplexers.

---Part 8: Strip bending test method for measuring the tensile properties of strip films. The purpose is to specify the method for measuring the tensile properties of films.

A method for testing the bending properties of strip.

---Part 9: Measurement of inter-wafer bonding strength. The purpose is to specify the testing methods for the bonding strength of MEMS wafers.

---Part 11: Test method for the linear thermal expansion coefficient of materials in suspended microelectromechanical systems. The purpose is to specify the linear thermal expansion coefficient of materials in suspended microelectromechanical systems.

Method for testing the linear thermal expansion coefficient of MEMS materials.

---Part 12: Bending Fatigue Testing Method for Thin Film Materials Using MEMS Structural Resonance. The purpose is to specify the testing methods for MEMS thin film materials.

Methods for testing the flexural fatigue of membrane materials.

---Part 13: Bending and Shear Test Methods for Bond Strength of MEMS Structures. The purpose is to specify the bonding strength of MEMS structures.

Strength test method.

---Part 16: Test methods for residual stress in MEMS films using wafer curvature and cantilever beam deflection. The purpose is to specify the testing methods for MEMS films.

Two test methods were used. residual stress wafer curvature and cantilever beam deflection.

---Part 19: Electronic Compass. The purpose is to define the terminology, characteristics, and testing methods for electronic compasses.

---Part 21: Methods for Measuring Poisson's Ratio of MEMS Thin Film Materials. The purpose is to specify methods for measuring the Poisson's ratio of MEMS thin film materials.

method.

---Part 22: Electromechanical Tensile Testing Methods for Conductive Thin Films on Flexible Substrates. The purpose is to specify the requirements for conductive thin film materials in MEMS.

Electromechanical property tensile test method.

---Part 26: Description and Measurement Methods for Microgrooves and Needle Structures. The aim is to define the description and measurement methods for MEMS microgrooves and needle structures.

Description and experimental methods.

---Part 27: Miniature V-T Test (MCT) Method for Measuring Glass Slurry Bond Strength. The purpose is to specify the glass fusion bond strength.

The MCT test method for the bond strength of the structure.

---Part 29: Electromechanical Relaxation Test Methods for Suspended Conductive Thin Films at Room Temperature. The purpose is to specify the electromechanical relaxation test methods for suspended conductive thin films in MEMS devices.

Electromechanical relaxation test method for thin films at room temperature.

---Part 32: Nonlinear Vibration Testing Methods for MEMS Resonators. The purpose is to define the nonlinear vibration characteristics of MEMS resonators.

Performance testing methods.

---Part 35: Test methods for electrical characteristics of flexible MEMS devices under bending deformation. The purpose is to specify the electrical characteristics of flexible